

Tutorial Day program

08.30-08.55		Registration
08.55-09.00		Opening
09.00-10.00	Noa Marom <i>Tulane University, USA</i>	Introduction to Density Functional Theory (DFT) and its Application to Defects in Semiconductors
10.00-10.30		Coffee break
10.30-11.30	Lasse Vines <i>University of Oslo, Norway</i>	Electrical Characterization of Deep Level Defects using Junction Spectroscopy
11.30-12.30	Evan Glaser <i>Naval Research Laboratory, USA</i>	Defect Spectroscopy of Semiconductors using Magnetic Resonance Techniques
12.30-13.30		Lunch
13.30-14.30	Reinhard Krause-Rehberg <i>Martin-Luther-University Halle, Germany</i>	Positron Annihilation Spectroscopy on Defects in Semiconductors
14.30-15.00		Coffee break
15.00-16.00	Alan Drew <i>Queen Mary University of London, UK</i>	Muon Spectroscopy Applied to Semiconductor Materials
16.00-16.05		Closing
16.05-19.00		Free time
19.00-23.30		Tutorial Day dinner

Locations

Tutorial day:

Aalto University main building, Otaniemi campus

Otakaari 1, Espoo

Lecture hall C

Dinner:

Restaurant Ranta

Radisson Blu Hotel

Otaranta 2, Espoo

